Benha University Faculty of Engineering at Shoubra Energy Engineering Dep.	Final Term Exam Date: Saturday (18/05/2019) Subject: Electronic Engineering Duration: 2 hours
Answer all the following questions	No. of questions : 3
The exam is in one Page	<ul> <li>Total Mark: 40 Marks</li> </ul>

## Question (1) (10 Marks)

(a) What are the ratings of  $V_{IN}$  in figure (1) if  $I_{Zmin}=0.25$  mA,  $P_z(max)=1$  W,  $V_z=10$  V. [5 marks]



(b) Draw the output from the following circuit in figure (2)



## Question (2) (10 Marks)

For the transistor shown in figure (3), find Ic ,  $I_B$  ,  $I_E$ , Vc ,  $V_B$ ,  $V_E$ ,  $V_{CE}$ ,  $V_{BE}$ ,  $V_{CB}$  if  $\beta = 150$ .



Question (3) (20Marks)

- (a) Draw the logic diagram for the Boolean function (F = AB + BC + AC)
- (b) Draw only the symbol of AND, OR, NOT, XNOR and XOR gates
- (c) Design OPAMP circuit to achieve the function Vout/Vin = +0.5
- (d) Design OPAMP circuit to achieve the function  $V_{out} = -(3V_1+2V_2)$

If it scares you, it might be a good thing to try Dr. Moataz Elsherbini

## **Model Answer**

Q1-a

$$I_{ZM} = \frac{P_{D(max)}}{V_Z} = \frac{1 \text{ W}}{10 \text{ V}} = 100 \text{ mA}$$
$$V_R = I_{ZK}R = (0.25 \text{ mA})(220 \Omega) = 55 \text{ mV}$$
$$V_{IN(min)} = V_R + V_Z = 55 \text{ mV} + 10 \text{ V} = 10.055 \text{ V}$$
$$V_R = I_{ZM}R = (100 \text{ mA})(220 \Omega) = 22 \text{ V}$$
$$V_{IN(max)} = 22 \text{ V} + 10 \text{ V} = 32 \text{ V}$$

Q1-b



Q2

$$I_{\rm B} = \frac{V_{\rm BB} - V_{\rm BE}}{R_{\rm B}} = \frac{5 \,\mathrm{V} - 0.7 \,\mathrm{V}}{10 \,\mathrm{k}\Omega} = 430 \,\mu\mathrm{A}$$
$$I_{\rm C} = \beta_{\rm DC}I_{\rm B} = (150)(430 \,\mu\mathrm{A}) = 64.5 \,\mathrm{mA}$$
$$I_{\rm E} = I_{\rm C} + I_{\rm B} = 64.5 \,\mathrm{mA} + 430 \,\mu\mathrm{A} = 64.9 \,\mathrm{mA}$$

Solve for VCE and VCB.

$$V_{CE} = V_{CC} - I_C R_C = 10 \text{ V} - (64.5 \text{ mA})(100 \Omega) = 10 \text{ V} - 6.45 \text{ V} = 3.55 \text{ V}$$
$$V_{CE} = V_{CE} - V_{BE} = 3.55 \text{ V} - 0.7 \text{ V} = 2.85 \text{ V}$$

Since the collector is at a higher voltage than the base, the collector-base junction is reverse-biased.









ENOR

c) ..



 $1^{st}$  stage Vo1 / Vin = - Rf1/R1 = -0.5  $2^{nd}$  stage Vo/ Vo1 = -1 Total gain =  $1^{st} * 2^{nd} = +0.5$ 

**d)..** 



Vo = - (RF/R2 \* V2 - RF/R1\*V1) = - (3V1 + 2V2) So RF/R2 = 3  $\rightarrow$  let Rf =6K $\Omega$  & R2 = 2K $\Omega$ RF/R1 = 2  $\rightarrow$  RF=6K $\Omega$  & R1 = 3K $\Omega$